

HI-8585, HI-8586

November 2004

ARINC 429 LINE DRIVER

DESCRIPTION

The HI-8585 and HI-8586 are CMOS integrated circuits designed to directly drive the ARINC 429 bus in an 8-pin package. Two logic inputs control a differential voltage between the output pins producing a +10 volt One, a -10 volt Zero, and a 0 volt Null.

The CMOS/TTL control inputs are translated to ARINC specified amplitudes using on board zeners. A logic input is provided to control the slope of the differential output signal. Timing is set by on-chip resistor and capacitor and tested to be within ARINC requirements.

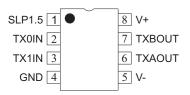
The HI-8585 has 37.5 ohms in series with each line driver output. The HI-8586 provides the option to bypass most of the output resistance so that external series protection circuits can add their resistances.

The HI-8585 or the HI-8586 along with the HI-8588 line receiver offer the smallest options available to get on and off the ARINC bus.

FEATURES

- Direct ARINC 429 line driver interface in a small package
- On-chip zener to set output levels
- On-chip line driver slope control and selection by logic input
- Low current 12 to 15 volt supplies
- CMOS / TTL logic pins
- Plastic and ceramic package options surface mount and DIP
- Thermally enhanced SOIC packages
- Mil processing available

PIN CONFIGURATION



SUPPLY VOLTAGES

V+ = 12V to 15VV- = -12V to -15V

FUNCTION TABLE

| TX1IN | TX0IN | SLP1.5 | TXAOUT | TXBOUT | SLOPE |
|-------|-------|--------|--------|--------|-------|
| 0 | 0 | Х | 0V | 0V | N/A |
| 0 | 1 | 0 | -5V | 5V | 10μs |
| 0 | 1 | 1 | -5V | 5V | 1.5μs |
| 1 | 0 | 0 | 5V | -5V | 10μs |
| 1 | 0 | 1 | 5V | -5V | 1.5μs |
| 1 | 1 | Х | 0V | 0V | N/A |

PIN DESCRIPTION TABLE

| PIN | SYMBOL | FUNCTION | DESCRIPTION |
|-----|---------|-------------|------------------------|
| 1 | SLP 1.5 | LOGIC INPUT | CMOS OR TTL, V+ IS OK |
| 2 | TX0IN | LOGIC INPUT | CMOS OR TTL |
| 3 | TX1IN | LOGIC INPUT | CMOS OR TTL |
| 4 | GND | POWER | GROUND |
| 5 | V- | POWER | -12 TO -15 VOLTS |
| 6 | TXAOUT | OUTPUT | LINE DRIVER TERMINAL A |
| 7 | TXBOUT | OUTPUT | LINE DRIVER TERMINAL B |
| 8 | V+ | POWER | +12 TO +15 VOLTS |

FUNCTIONAL DESCRIPTION

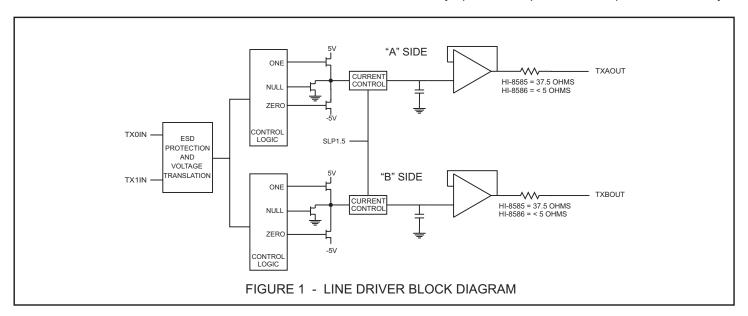
Figure 1 is a block diagram of the line driver. The +5V and -5V levels are generated internally using on-chip zeners. Currents for slope control are set by zener voltages across on-chip resistors.

The TX0IN and TX1IN inputs receive logic signals from a control transmitter chip such as the HI-6010, HI-3282 or HI-8282. TXAOUT and TXBOUT hold each side of the ARINC bus at Ground until one of the inputs becomes a One. If for example TX1IN goes high, a charging path is enabled to 5V on an "A" side internal capacitor while the "B" side is enabled to -5V. The charging current is selected by the SLP1.5 pin. If the SLP1.5 pin is high, the capacitor is nominally charged from 10% to 90% in 1.5 μ s. If SLP1.5 is low, the rise and fall times are 10 μ s.

A unity gain buffer receives the internally generated slopes and differentially drives the ARINC line. Current is limited by the series output resistors at each pin. There are no fuses at the outputs of the HI-8585 as exists on the HI-8382.

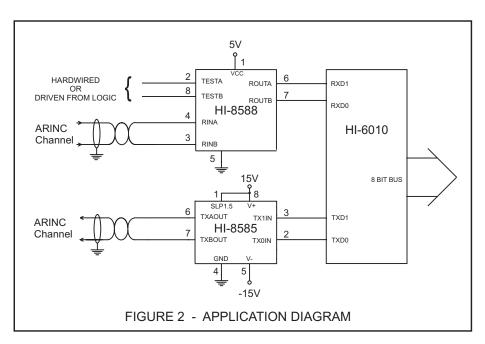
The HI-8585 has 37.5 ohms in series with each output. The HI-8586 has less than 5 ohms in series. The HI-8586 is for applications where external series resistance is required, typically for lightning protection devices.

Both the HI-8585 and HI-8586 are built using high-speed CMOS technology. Care should be taken to ensure the V+ and V- supplies are locally decoupled and that the input waveforms are free from negative voltage spikes which may upset the chip's internal slope control circuitry.



APPLICATION INFORMATION

Figure 2 shows a possible application of the HI-8585/86 interfacing an ARINC transmit channel from the HI-6010.



ABSOLUTE MAXIMUM RATINGS

Voltages referenced to Ground

| Supply voltages V+20V V20V |
|--|
| DC current per input pin +10mA |
| Power dissipation at 25°C plastic DIL1.0W, derate 10mW/°C ceramic DIL0.5W, derate 7mW/°C |
| Solder Temperature275°C for 10 sec |
| Storage Temperature65°C to +150°C |

RECOMMENDED OPERATING CONDITIONS

| | V ± 5% or +15V ±10% V ± 5% or -15V ±10% |
|-------------------|--|
| Hi-Temp Screening | j40°C to +85°C 55°C to +125°C 55°C to +125°C |

NOTE: Stresses above absolute maximum ratings or outside recommended operating conditions may cause permanent damage to the device. These are stress ratings only. Operation at the limits is not recommended.

DC ELECTRICAL CHARACTERISTICS

V+ = +12V to +15V, V- = -12V to -15V, $T_A = Operating Temperature Range (unless otherwise stated)$

| PARAMETERS | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---|----------------------------|--|-------------------------|----------------------|------------------------|-------------------------|
| Input voltage (TX1IN, TX0IN, SLP1.5) high low | VIH VIL | | 2.1 - | | V+ 0.5 | volts volts |
| Input current (TX1IN, TX0IN, SLP1.5) source sink | lih lil | VIN = 0V VIN = 5V | - | | 0.1 0.1 | μΑ μΑ |
| ARINC output voltage (Differential) one zero null | VDIFF1 VDIFF0 VDIFFN | no load; TXAOUT - TXBOUT no load; TXAOUT - TXBOUT no load; TXAOUT - TXBOUT | 9.00 -11.00 -0.50 | 10.00 -10.00 0 | 11.00 -9.00 0.50 | volts volts volts |
| ARINC output voltage (Ref. to GND) one or zero null | VDOUT VNOUT | no load & magnitude at pin no load | 4.50 -0.25 | 5.00 0 | 5.50 0.25 | volts volts |
| Operating supply current V+ V- | IDD IEE | SLP1.5 = V+ TX1IN & TX0IN = 0V: no load TX0IN & TX1IN = 0V: no load | | 6.0 -6.0 | 14.0 - | mA mA |
| ARINC output impedence HI-8585 HI-8586 | Zout | | - | 37.5 - | - 5 | ohms ohms |

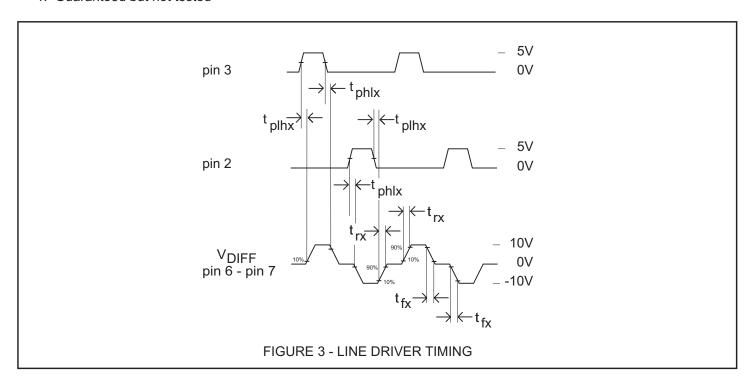
AC ELECTRICAL CHARACTERISTICS

V+ = 15.0V, V- = -15V, T_A = Operating Temperature Range (unless otherwise stated)

| PARAMETERS | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------------------|-----------------|------------------------------|-----|------|------|-------|
| Line Driver propagation delay | | defined in Figure 3, no load | | | | |
| Output high to low | t phlx | | - | 500 | - | ns |
| Output low to high | t plhx | | - | 500 | - | ns |
| Line Driver transition times | | | | | | |
| High Speed | | SLP 1.5 = V+ | | | | |
| Output high to low | t fx | pin 1 = logic 1 | 1.0 | 1.5 | 2.0 | μs |
| Output low to high | t _{rx} | pin 1 = logic 1 | 1.0 | 1.5 | 2.0 | μs |
| Low Speed | | SLP 1.5 = GND | | | | |
| Output high to low | t fx | pin 1 = logic 1 | 5.0 | 10.0 | 15.0 | μs |
| Output low to high | t rx | pin 1 = logic 1 | 5.0 | 10.0 | 15.0 | μs |
| Input capacitance (1) | | | | | | |
| logic | C _{IN} | | - | - | 10 | pF |

Notes:

1. Guaranteed but not tested



PACKAGE THERMAL CHARACTERISTICS

MAXIMUM ARINC LOAD 9

| PACKAGE STYLE 1 | ARINC 429 | SUPPL | Y CURREN | T (mA) ² | JUNCTION TEMP, Tj (°C) | | | |
|-----------------------------------|-------------------------|-----------|-----------|---------------------|------------------------|-----------|----------|--|
| FACRAGE STILL | DATA RATE | Ta = 25°C | Ta = 85°C | Ta=125°C | Ta = 25°C | Ta = 85°C | Ta=125°C | |
| 8 Lead Plastic DIP | Low Speed ³ | 16.8 | 17.2 | 16.9 | 58 | 116 | 157 | |
| o Leau Flasiic Dir | High Speed ⁴ | 27.3 | 26.7 | 25.9 | 75 | 132 | 169 | |
| 8 Lead Plastic ESOIC ⁵ | Low Speed | 17.4 | 17.5 | 16.9 | 68 | 126 | 166 | |
| o Lead Plastic ESOIC | High Speed | 27.6 | 27.1 | 25.9 | 97 | 147 | 186 | |
| 8 Lead Plastic ESOIC ⁶ | Low Speed | 17.1 | 17.2 | 16.7 | 52 | 110 | 151 | |
| o Lead Plastic ESOIC | High Speed | 27.3 | 27.1 | 26.2 | 57 | 112 | 157 | |

TXAOUT and TXBOUT Shorted to Ground 7, 8, 9

| PACKAGE STYLE 1 | ARINC 429 | SUPPLY CURRENT (mA) ² | | | JUNCTION TEMP, Tj (°C) | | | |
|-----------------------------------|-------------------------|----------------------------------|-----------|----------|------------------------|-----------|----------|--|
| FACRAGE STILL | DATA RATE | Ta = 25°C | Ta = 85°C | Ta=125°C | Ta = 25°C | Ta = 85°C | Ta=125°C | |
| 0 D D D | Low Speed ³ | 53.6 | 50.7 | 52.2 | 131 | 181 | 217 | |
| 8 Lead Plastic DIP | High Speed ⁴ | 46.9 | 38.7 | 42.5 | 135 | 181 | 219 | |
| | Low Speed | 46.4 | 47.6 | 68.1 | 167 | 191 | 221 | |
| 8 Lead Plastic ESOIC ⁵ | High Speed | 42.1 | 43.8 | 67.1 | 177 | 212 | 223 | |
| 8 Lead Plastic ESOIC ⁶ | Low Speed | 48.5 | 45.6 | 46.1 | 112 | 161 | 186 | |
| o Lead Plastic ESOIC | High Speed | 46.8 | 41.1 | 40.5 | 116 | 168 | 197 | |

Notes:

- 1. All data taken in still air on devices soldered to single layer copper PCB (3" X 4.5" X .062").
- 2. At 100% duty cycle, 15V power supplies. For 12V power supplies multiply all tabulated values by 0.8.
- 3. Low Speed: Data Rate = 12.5 Kbps, Load: R = 400 Ohms, C = 30 nF.
- 4. High Speed: Data Rate = 100 Kbps, Load: R = 400 Ohms, C = 10 nF. Data not presented for C = 30 nF as this is considered unrealistic for high speed operation.
- 5. 8 Lead Plastic ESOIC (Thermally enhanced SOIC with built in heat sink). Heat sink not soldered to the PCB.
- 6. 8 Lead Plastic ESOIC (Thermally enhanced SOIC with built in heat sink). Heat sink soldered to the PCB.
- 7. Similar results would be obtained with TXAOUT shorted to TXBOUT.
- 8. For applications requiring survival with continuous short circuit, operation above Tj = 175°C is not recommended.
- 9. Data will vary depending on air flow and the method of heat sinking employed.

HEAT SINK - ESOIC PACKAGES

An 8-pin thermally enhanced SOIC package is used for the HI-8585/HI-8586 products. The ESOIC package includes a metal heat sink located on the bottom surface of the device. This heat sink should be soldered down to the printed circuit board for optimum thermal dissipation. The

heat sink is electrically isolated from the chip and can be soldered to any ground or power plane. However, since the chip's substrate is at V+, connecting the heat sink to this power plane is recommended to avoid coupling noise into the circuit.

ORDERING INFORMATION

| PART NUMBER | PACKAGE DESCRIPTION | TEMPERATURE RANGE | FLOW | BURN IN | LEAD FINISH |
|----------------|--------------------------|----------------------|------|------------|----------------|
| HI-8585PDI | 8 PIN PLASTIC DIP | -40°C T0 +85°C | I | NO | SOLDER |
| HI-8585PDT | 8 PIN PLASTIC DIP | -55°C T0 +125°C | Т | NO | SOLDER |
| HI-8585PDM | 8 PIN PLASTIC DIP | -55°C T0 +125°C | М | YES | SOLDER |
| HI-8585PSI | 8 PIN PLASTIC ESOIC - NB | -40°C T0 +85°C | I | NO | SOLDER |
| HI-8585PST | 8 PIN PLASTIC ESOIC - NB | -55°C T0 +125°C | Т | NO | SOLDER |
| HI-8585PSM | 8 PIN PLASTIC ESOIC - NB | -55°C T0 +125°C | М | YES | SOLDER |
| HI-8585CRI | 8 PIN CERDIP | -40°C T0 +85°C | 1 | NO | SOLDER |
| HI-8585CRT | 8 PIN CERDIP | -55°C T0 +125°C | Т | NO | SOLDER |
| HI-8585CRM | 8 PIN CERDIP | -55°C T0 +125°C | М | YES | SOLDER |
| HI-8586PDI | 8 PIN PLASTIC DIP | -40°C T0 +85°C | I | NO | SOLDER |
| HI-8586PDT | 8 PIN PLASTIC DIP | -55°C T0 +125°C | Т | NO | SOLDER |
| HI-8586PDM | 8 PIN PLASTIC DIP | -55°C T0 +125°C | М | YES | SOLDER |
| HI-8586PSI | 8 PIN PLASTIC ESOIC - NB | -40°C T0 +85°C | I | NO | SOLDER |
| HI-8586PST | 8 PIN PLASTIC ESOIC - NB | -55°C T0 +125°C | Т | NO | SOLDER |
| HI-8586PSM | 8 PIN PLASTIC ESOIC - NB | -55°C T0 +125°C | М | YES | SOLDER |
| HI-8586CRI | 8 PIN CERDIP | -40°C T0 +85°C | I | NO | SOLDER |
| HI-8586CRT | 8 PIN CERDIP | -55°C T0 +125°C | Т | NO | SOLDER |
| HI-8586CRM | 8 PIN CERDIP | -55°C T0 +125°C | М | YES | SOLDER |

Legend: ESOIC - Thermally Enhanced Small Outline Package (SOIC w/built-in heat sink) NB - Narrow Body



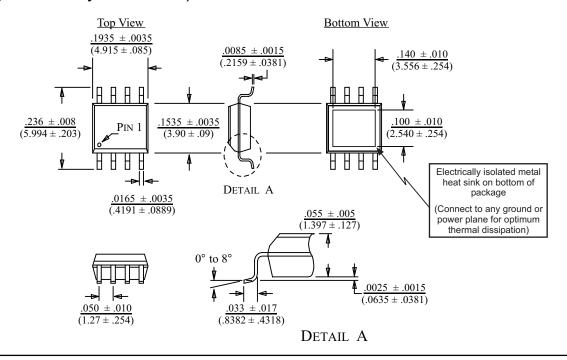
HI-8585 / HI-8586 PACKAGE DIMENSIONS

inches (millimeters)

8-PIN PLASTIC SMALL OUTLINE (ESOIC) - NB

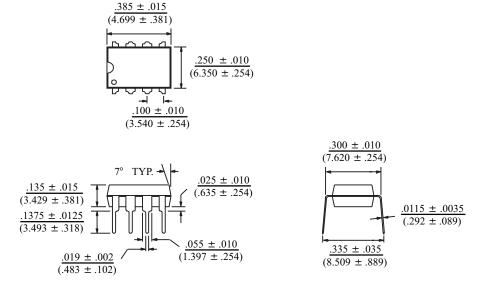
(Narrow Body, Thermally Enhanced)

Package Type: 8HNE



8-PIN PLASTIC DIP

Package Type: 8P





HI-8585 / HI-8586 PACKAGE DIMENSIONS

inches (millimeters)

